

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Original) A semiconductor integrated circuit device comprising:
an input conductor that is connected from outside to an input circuit operating on a first power source voltage; and
an output conductor leading to an outside that is adjacent to the input conductor and is connected to an output side of a switch element operating on a second power source voltage that is higher than the first power source voltage,
wherein, upon detecting that a voltage higher than a reference voltage is inputted to the input conductor, an output from the output side of the switch element connected to the output conductor adjacent to the input conductor is inhibited.
2. (Original) A semiconductor integrated circuit device comprising:
an output portion that outputs a predetermined voltage to an outside from a voltage output terminal via a switch element; and
a control portion that can control and open the switch element when a voltage inputted to an voltage input terminal from outside is higher than a reference voltage,
wherein the voltage input terminal is so arranged as to be adjacent to the voltage output terminal.
3. (Original) A semiconductor integrated circuit device comprising:

an output portion that outputs a pulse voltage obtained by switching a direct-current voltage with a switch element to an external smoothing circuit from a voltage output terminal; and

a control portion that controls the switch element so that a feedback voltage based on an output voltage of the smoothing circuit becomes equal to a reference voltage, the output voltage being inputted from outside to a voltage input terminal,

wherein the voltage input terminal is so arranged as to be adjacent to the voltage output terminal.

4. (Original) A semiconductor integrated circuit device comprising:

an output portion that outputs via a switch element a predetermined voltage to an outside from a voltage output terminal through a voltage output line; and

a control portion that performs predetermined control based on a control signal inputted from outside to a signal input line or a signal input terminal that is so arranged as to be adjacent to the voltage output line or the voltage output terminal,

wherein there is provided a voltage detection portion that detects that a voltage higher than a reference voltage is inputted to the signal input line or the signal input terminal and feeds a resultant voltage to the output portion as a voltage detection signal, and

wherein the output portion opens the switch element when the voltage detection signal is provided thereto.

5. (Original) The semiconductor integrated circuit device of claim 4,

wherein the output portion includes

a drive circuit that generates a driving signal for driving the switch element,
and

a logic gate that takes an AND of the driving signal and the voltage detection signal and then feeds a resulting output to a control terminal of the switch element.

6. (Original) The semiconductor integrated circuit device of claim 4,
wherein the voltage detection portion includes
a first transistor that turns on when a voltage at the signal input terminal is
higher than the reference voltage, and
a second transistor that forms a current mirror circuit together with the first
transistor, and
wherein the voltage detection signal is outputted from a node at which a resistor
that pulls up the second transistor and the second transistor are connected together.
7. (Original) The semiconductor integrated circuit device of claim 6,
wherein the voltage detection portion further includes a diode in a current path
between the signal input terminal and the first transistor, and
wherein a value obtained by adding a forward voltage of the diode and a base-
emitter voltage of the first transistor is equivalent to the reference voltage.
8. (Original) A semiconductor integrated circuit device comprising:
an output portion that outputs a predetermined voltage to an outside of the device
from a voltage output terminal via a switch element that is closed/opened based on an
output control signal provided from an external control device;
a reset input terminal that receives a reset input signal from outside; and
a control portion that feeds to the external control device a reset output signal that
causes the external control device to stop an output operation of the output control signal
when a voltage of the reset input signal is higher than a reference voltage,
wherein the reset input terminal is so arranged as to be adjacent to the voltage
output terminal.
9. (Currently Amended) The semiconductor integrated circuit device of claim 1 ~~one of claims 1~~
~~to 8~~,
wherein a breakdown voltage of the switch element is higher than a breakdown
voltage of the control portion.

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10. (Original) A switching power source device,
wherein the semiconductor integrated circuit device of claim 3 is adopted.